



polyfet rf devices

MDDQ02

Power RF Amplifiers

Power = 15.0 Watts

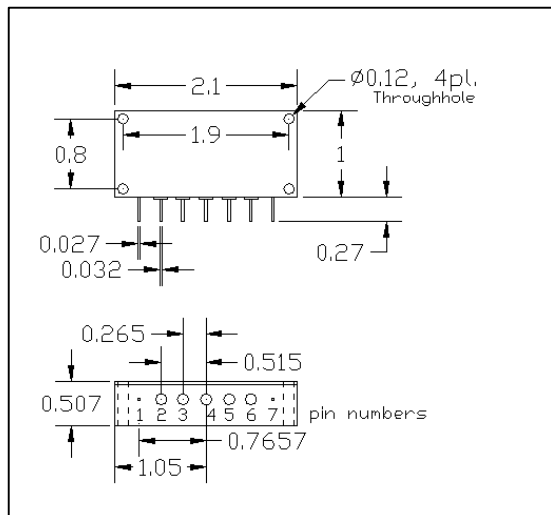
Bandwidth = 30 to 512 Mhz

Gain = 25.0 dB Vdd = 28.0 Volts

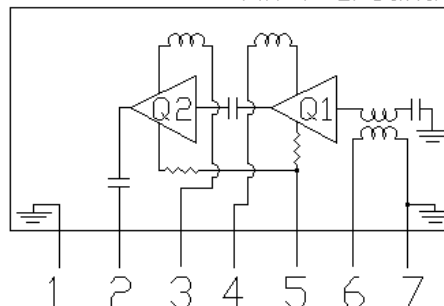
50 ohms Input/Output Impedance

Description

The MDDQ02 is a 15 Watt, 2 stage high gain amplifier module covering a bandwidth of 30-512 Mhz. This compact module design is suitable for military applications in a rugged environment. An ALC pin is provided to control the output power of the module. The MDDQ02 may be used as the driver stage for the MBDQ01 module.



Pin 1=Ground Pin 4=Vdd 2
Pin 2=RF out Pin 5=VAGC
Pin 3=Vdd 1 Pin 6=RF in
Pin 7=Ground



Absolute Maximum Ratings (T=25 °C)

Parameter	Symbol	Value	Unit
DC supply Voltage 1	VDD1	32.0	V
DC supply Voltage 2	VDD2		V
AGC Voltage	VAGC	8.00	V
Input Power	Pin	0.05	W
Output Power	Pout	20.0	W
Operating Case Temp.	Tc	-20 to +85	°C
Storage Temperature	Tstg	-30 to +100	°C

Electrical Characteristics: (T=25 °C Zs=Zl=50 ohms. Vdd= 28.0 Volts)

Parameter	Symbol	Min	Typical	Max	Unit	Test Conditions
Frequency Range	BW	30		512	Mhz	50 ohm load
Outut Power	Po	15.0			Watts	Idq = 2.00 Amps
Power Gain	PG	25.0			dB	@ Pout = 15.0 Watts
Total Efficiency	η	15			%	@ Pout = 15.0 Watts
2nd Harmonics	dso		-20.00		dBc	@ Pout = 15.0 W. Freq = 270 Mhz
Intermod - 2 tone	Ip3				dBm	Freq = 270 Mhz; AvePwr= W
Load Mismatch Tolerance	VSWR	10:1			Relative	All Phase Angles

POLYFET RF DEVICES

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